

Photo DMOS - FET Relay I PMA216D

RELAY / ISO9001 / IATF16949 CERTIFIED

Features

- High reliability
- Arc-Free with no snubbing circuits
- 1500Vrms Input / Output isolation
- Tape & Reel version available
- Low driver power requirements (TTL/CMOS Compatible)
- SOP package 4 Pin type in miniature design (4.4 x 4.3 x 2.0mm)



Description

The PMA216D is a miniature 1-Form A solid state relay in a 4 pin SOP package that employs optically coupled MOSFET technology to provide 1500V of input to output isolation. The optically coupled input is controlled by a highly efficient GaAlAs infrared LED and MOS FETs on the output side.

Application

Telecommunications (PC, Electronic notepad) / Measuring and Testing Equipment / Industrial Control / Security Equipments / High Speed Inspection Machine, Data Communication Equipments, Factory Automotive Equipments, etc.

Absolute Maximum Ratings (Ambient Temperature: 25[°]C)

Item		Symbol	Value	Units	Note
Input	Continuous LED Current	I _F	50	mA	
	Peak LED Current	I _{FP}	1000	mA	f=100Hz, duty=1%
	LED Reverse Voltage	V_R	5	V	
	Input Power Dissipation	P_ln	75	mW	

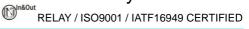
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Absolute Maximum Ratings (Ambient Temperature: 25°C)

Item		Symbol	Value	Units	Note
Output	Load Voltage	V_L	20	VDC	
	Load Current	ΙL	5	Α	
	Peak Load Current	I _{Peak}	35	Α	300µs (1 pulse)
	Output Power Dissipation	P _{out}	1.8	W	
Total Power Dissipation		P_{T}	2	W	
I/O Breakdown Voltage		$V_{I/O}$	1500	Vrms	RH=60%, 1min
Operating Temperature		T_{Opr}	-40 to +85	$^{\circ}\!\mathbb{C}$	
Storage Temperature		T_{Stg}	-40 to +100	$^{\circ}\!\mathbb{C}$	
Pin Soldering Temperature		T_{Sol}	260	$^{\circ}\!\mathbb{C}$	10 sec max.

Electrical Specifications (Ambient Temperature: 25°C)

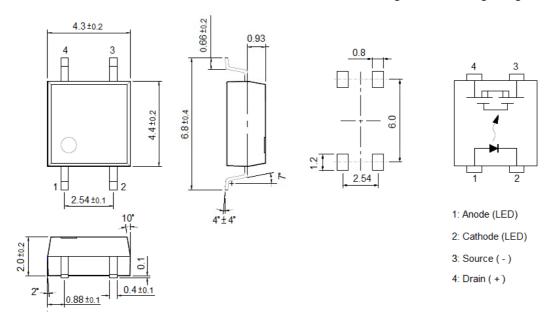
Item		Symbol	MIN.	TYP.	MAX.	Units	Note
Input	LED Forward Voltage	V_{F}		1.2	1.4	V	I _F =10mA
	Operation LED Current	I _{F On}		0.5	2.0	mA	
	Recovery LED Current	I_{FOff}		0.35	0.5	mA	
	Recovery LED Voltage	V_{FOff}	0.5			٧	
Output	On-Resistance	R _{on}		0.2	0.5	Ω	I_F =5mA, I_L =100mA, Time to flow is within 1 sec.
	Off-State Leakage Current	I _{Leak}			1	μΑ	V _L =Rating
	Output Capacitance	C_Out		500		pF	V _L =0, f=1MHz
Transmission	Turn-On Time	T_On		0.5	1.5	ms	I _F =5mA,
	Turn-Off Time	T_{Off}		0.03	0.1	ms	I _L =100mA,
Coupled	I/O Isolation Resistance	R _{I/O}	10 ⁹			Ω	DC500V
	I/O Capacitance	C _{I/O}		0.8	1.5	pF	f=1MHz



Dimensions (UNIT: mm)

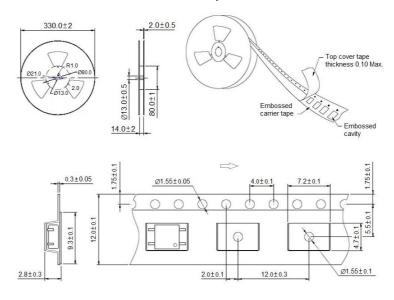
Outline Dimensions

Recommended Mounting Pad Wiring Diagram



Tape Packing

Direction of Relay Insertion



2,000pcs per reel, 2 reel per box, 5boxes per carton.

Engineering Data

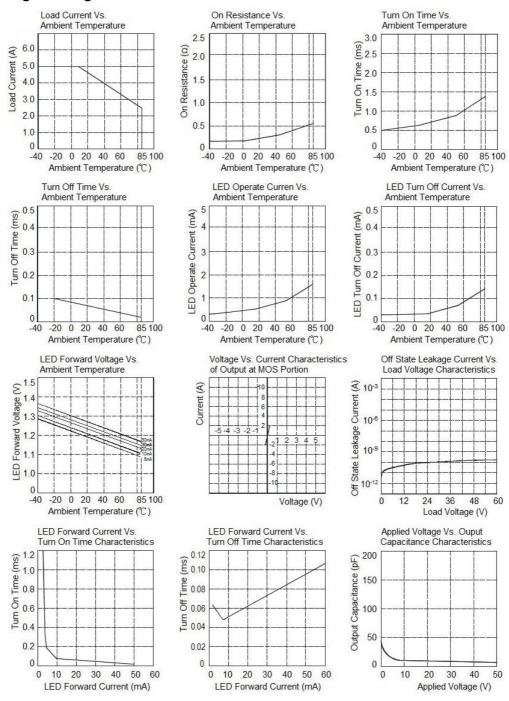


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Note:

- 1. There shall be leader of 230 mm minimum which may consist of carrier and or cover tape follower by a minimum of 160 mm of carrier tape sealed with cover tape.
- 2. There shall be a minimum of 160 mm of empty component pockets sealed with cover tape.
- 3. Devices are pockets in accordance with EIA standard EIA-481-A and specifications given above.

Remark: 1) In case of no tolerance shown in outline dimension: outline dimension \leq 1mm, tolerance should be \pm 0.2mm; outline dimension >1mm and \leq 5mm, tolerance should be \pm 0.3mm; outline dimension >5mm, tolerance should be \pm 0.5mm.

2) The tolerance without indicating for PCB layout is always ± 0.1 mm.

Disclaimer

The specification is for reference only. See to "Terminology and Guidelines" for more information. Specifications subject to change without notice. We could not evaluate all the performance and all the parameters for every possible application. Thus the user should be in a right position to choose the suitable product for their own application. If there is any query, please contact IOEC for the technical service. However, it is the user's responsibility to determine which product should be used only.

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